# N-Channel 200-V (D-S) MOSFET

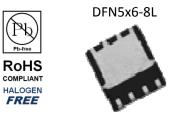
## **Key Features:**

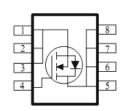
- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- Fast switching speed

### **Typical Applications:**

- White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
VDS (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
200	400 @ V <sub>GS</sub> = 10V	3	
200	450 @ V <sub>GS</sub> = 4.5V	2.8	





ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Limit	Units			
Drain-Source Voltage	V <sub>DS</sub>	200	V			
Gate-Source Voltage		V <sub>GS</sub>	±20	V		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	I <sub>D</sub>	3			
Continuous Drain Current	T <sub>A</sub> =70°C		2.4	А		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	20			
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	6.2	А		
Device Discipation <sup>a</sup>	T <sub>A</sub> =25°C	P <sub>D</sub>	5	w		
Power Dissipation <sup>a</sup>	T <sub>A</sub> =70°C	' D	3.2	vv		
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	R <sub>eja</sub>	25	°C/W			
	Steady State	٩٢٩	65				

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

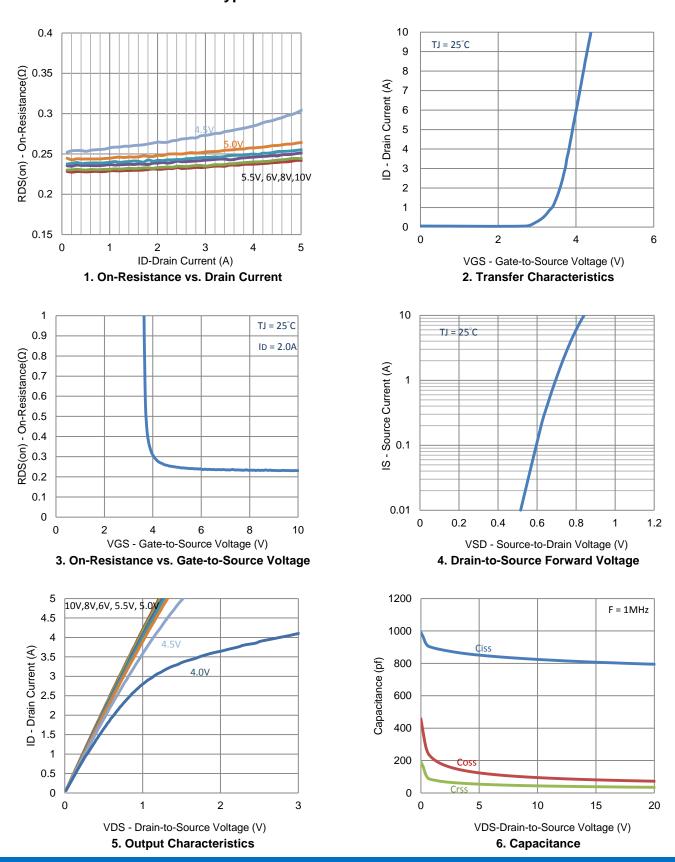
# **Electrical Characteristics**

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit		
Static								
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, ID = 250 \text{ uA}$	1			V		
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			±10	uA		
Zero Gate Voltage Drain Current		$V_{DS} = 160 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			1	uA		
	DSS	$V_{DS} = 160 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			10	uA		
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	10			А		
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 3.0 \text{ A}$			400	00 mΩ		
Drain-Source On-Resistance	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 2.8 \text{ A}$			450	11122		
Forward Transconductance	<b>g</b> <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 3.0 \text{ A}$		10		S		
Diode Forward Voltage	$V_{SD}$	$I_{S} = 3.1 \text{ A}, V_{GS} = 0 \text{ V}$		0.77		V		
		Dynamic						
Total Gate Charge	Qg			7.9		nC		
Gate-Source Charge	$Q_gs$	$V_{DS} = 100 \text{ V}, V_{GS} = 4.5 \text{ V}, \text{ ID} = 2.0 \text{ A}$		3.4				
Gate-Drain Charge	Q <sub>gd</sub>			3.9				
Turn-On Delay Time	t <sub>d(on)</sub>			3.7				
Rise Time	t <sub>r</sub>	$V_{\text{DD}}$ = 100 V, $R_{\text{L}}$ = 50 $\Omega$ , $I_{\text{D}}$ = 2.0 A,		8		20		
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GEN}$ = 10 V, $R_{GEN}$ = 6 $\Omega$		26		ns		
Fall Time	t <sub>f</sub>			12				
Input Capacitance	C <sub>iss</sub>			807				
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = 0 V, f =1 MHz		81		pF		
Reverse Transfer Capacitance	C <sub>rss</sub>			38				

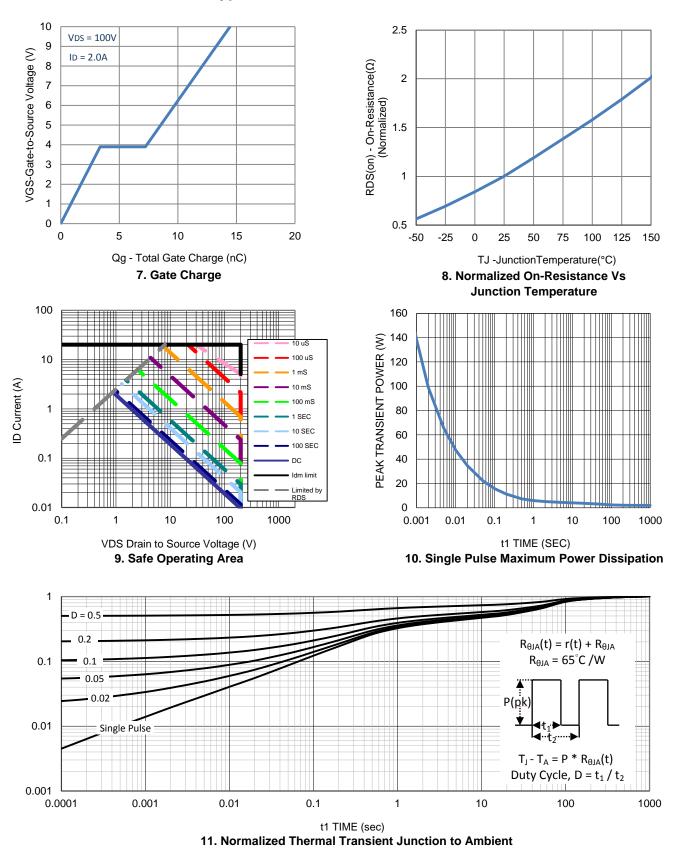
#### Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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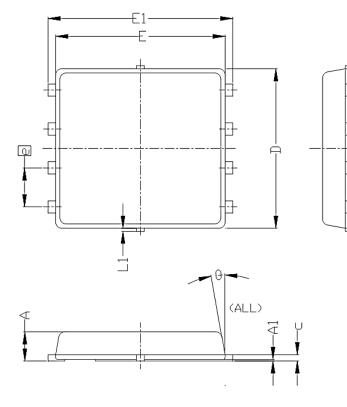
**Typical Electrical Characteristics** 

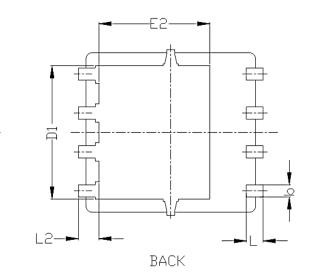


## **Typical Electrical Characteristics**

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# Package Information





SYMBOLS	DIMENSIONS IN MILLIMETERS			DIMENSIONS IN INCHES			
STNDOLS	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.85	0.95	1.00	0.033	0.037	0.039	
Al	0.00		0.05	0.000		0.002	
b	0.30	0.40	0.50	0.012	0.016	0.020	
с	0.15	0.20	0.25	0.006	0.008	0.010	
D	5. 20 BSC 0. 205 B			0.205 BSC			
D1	4.35 BSC			0.171 BSC			
E	5.55 BSC			0.219 BSC			
E1	6.05 BSC			0.238 BSC			
E2	3. 62 BSC 0. 143 BSC						
e	1.27 BSC			0.050 BSC			
L	0.45	0.55	0.65	0.018	0.022	0.026	
L1	0		0.15	0		0.006	
L2	0.68 REF			0.027 REF			
θ	0°		10°	0°		10°	